# NSN 5961-01-069-0374

Transistor - Page 1 of 1



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#### **Inclosure Material:**

Metal

#### **Overall Length:**

Between 0.250 inches and 0.450 inches

## **Overall Diameter:**

0.875 inches

## **Mounting Facility Quantity:**

2

#### Internal Configuration:

Junction contact

# Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

Features Provided:

#### Hermetically sealed case

Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

250.0 collector to base voltage/static/emitter open and 200.0 collector to emitter voltage/static/base open and 8.0 emitter to base voltage,

static, collector open

#### **Current Rating Per Characteristic:**

Between 10.00 amperes source cutoff current and 50.00 amperes source cutoff current

#### Power Rating Per Characteristic:

150.0 watts small-signal input power, common-collector preset

#### Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

#### **Special Features:**

Junction pattern arrangement: npn

#### Test Data Document:

35351-162495 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

#### **Terminal Type And Quantity:**

1 case and 2 pin Shelf Life: N/a Unit Of Measure: --Demilitarization: No Fiig:

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